



SANYO Semiconductors

DATA SHEET

An ON Semiconductor Company

ECH8672 — P-Channel Silicon MOSFET General-Purpose Switching Device Applications

Features

- 1.8V drive
- Composite type, facilitating high-density mounting
- Halogen free compliance

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		-20	V
Gate-to-Source Voltage	VGSS		±10	V
Drain Current (DC)	ID		-3.5	A
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	-30	A
Allowable Power Dissipation	PD	When mounted on ceramic substrate (1200mm ² ×0.8mm) 1unit	1.3	W
Total Power Dissipation	PT	When mounted on ceramic substrate (1200mm ² ×0.8mm)	1.5	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

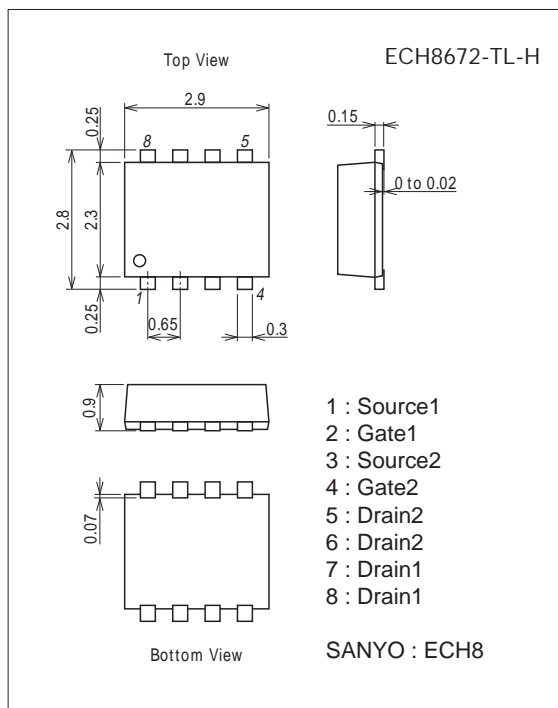
This product is designed to "ESD immunity < 200V**", so please take care when handling.

* Machine Model

Package Dimensions

unit : mm (typ)

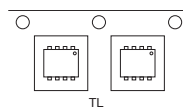
7011A-001



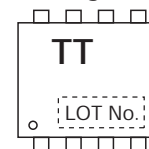
Product & Package Information

- Package : ECH8
- JEITA, JEDEC : -
- Minimum Packing Quantity : 3,000 pcs./reel

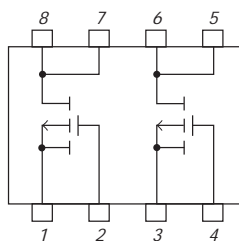
Packing Type : TL



Marking



Electrical Connection



SANYO Semiconductor Co., Ltd.

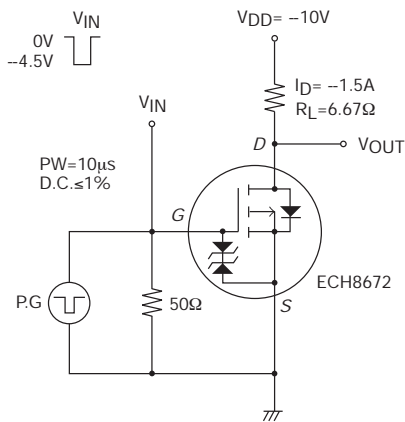
<http://semicon.sanyo.com/en/network>

ECH8672

Electrical Characteristics at Ta=25°C

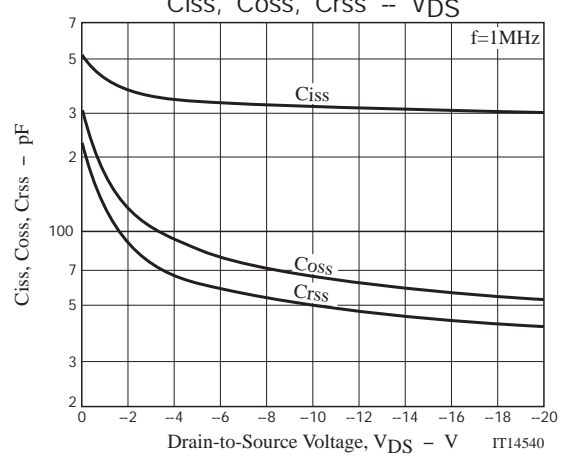
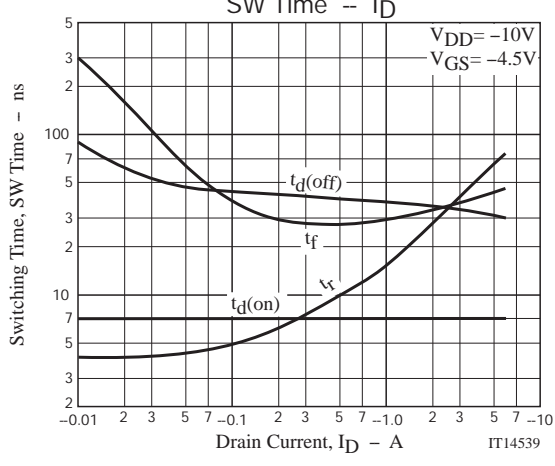
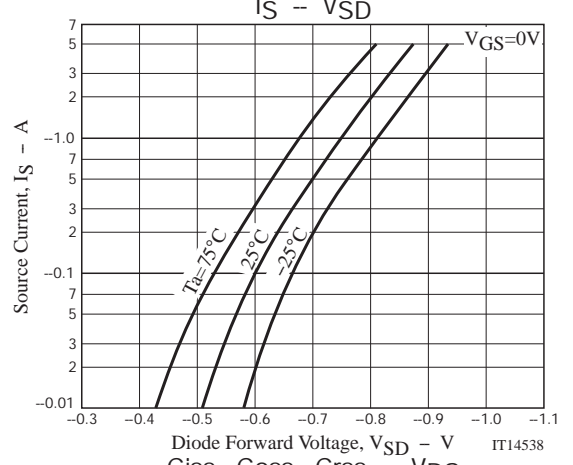
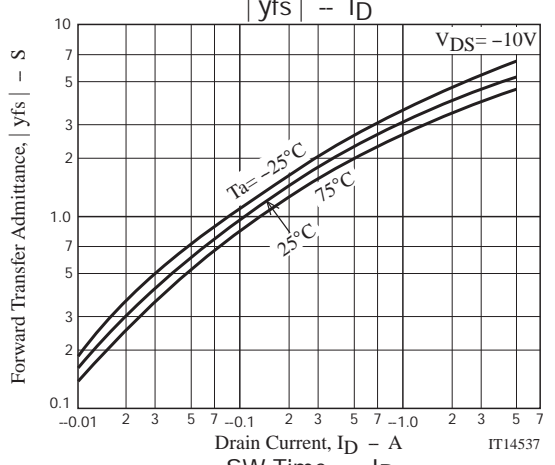
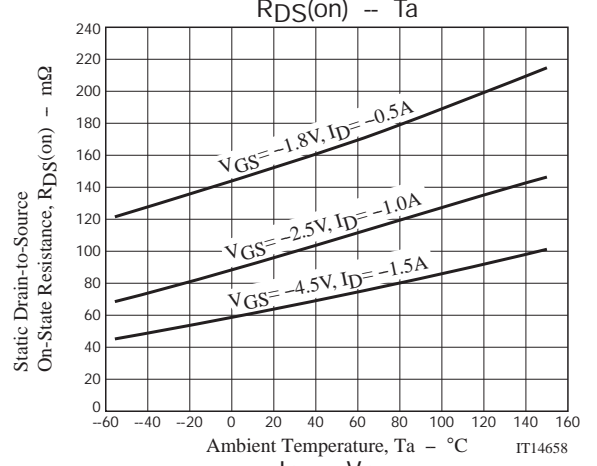
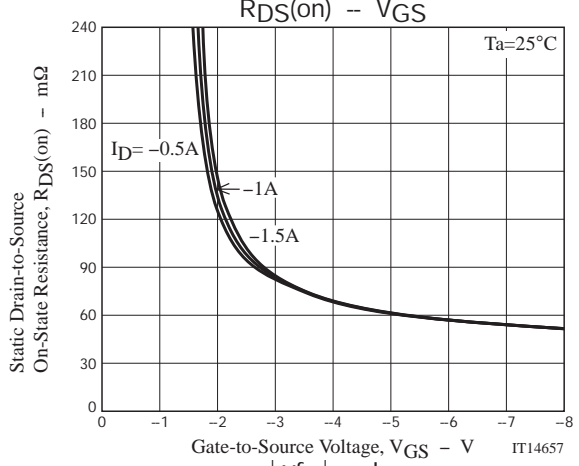
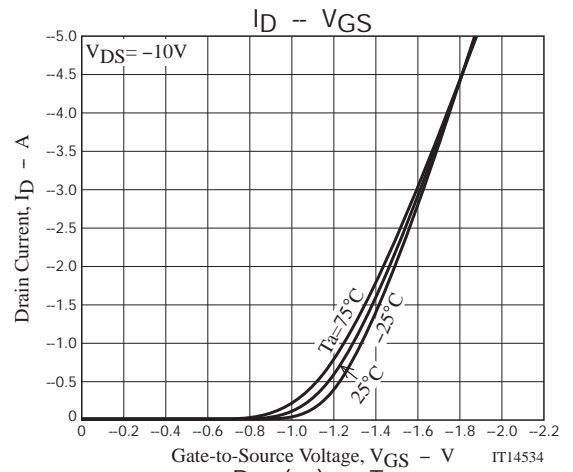
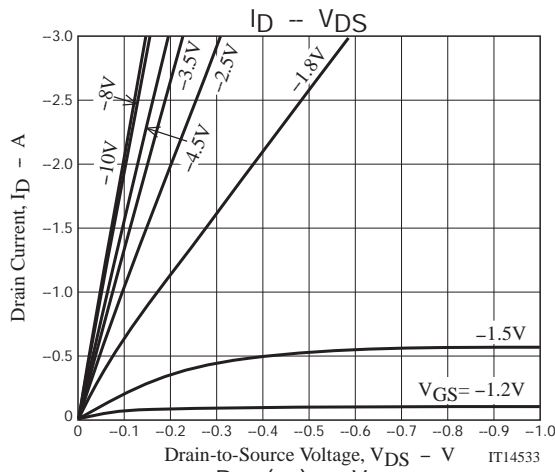
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D = -1\text{mA}, V_{GS} = 0\text{V}$	-20			V
Zero-Gate Voltage Drain Current	I_{DSS}	$V_{DS} = -20\text{V}, V_{GS} = 0\text{V}$			-1	μA
Gate-to-Source Leakage Current	I_{GSS}	$V_{GS} = \pm 8\text{V}, V_{DS} = 0\text{V}$			± 10	μA
Cutoff Voltage	$V_{GS(off)}$	$V_{DS} = -10\text{V}, I_D = -1\text{mA}$	-0.4		-1.3	V
Forward Transfer Admittance	$ y_{fs} $	$V_{DS} = -10\text{V}, I_D = -1.5\text{A}$	2.1	3.6		S
Static Drain-to-Source On-State Resistance	$R_{DS(on)1}$	$I_D = -1.5\text{A}, V_{GS} = -4.5\text{V}$		65	85	$\text{m}\Omega$
	$R_{DS(on)2}$	$I_D = -1\text{A}, V_{GS} = -2.5\text{V}$		98	137	$\text{m}\Omega$
	$R_{DS(on)3}$	$I_D = -0.5\text{A}, V_{GS} = -1.8\text{V}$		155	235	$\text{m}\Omega$
Input Capacitance	C_{iss}	$V_{DS} = -10\text{V}, f = 1\text{MHz}$		320		pF
Output Capacitance	C_{oss}			66		pF
Reverse Transfer Capacitance	C_{rss}			50		pF
Turn-ON Delay Time	$t_d(on)$		See specified Test Circuit.		7.1	
Rise Time	t_r			21		ns
Turn-OFF Delay Time	$t_d(off)$			37		ns
Fall Time	t_f			32		ns
Total Gate Charge	Q_g	$V_{DS} = -10\text{V}, V_{GS} = -4.5\text{V}, I_D = -3.5\text{A}$			4.0	
Gate-to-Source Charge	Q_{gs}			0.6		nC
Gate-to-Drain "Miller" Charge	Q_{gd}			1.1		nC
Diode Forward Voltage	V_{SD}	$I_S = -3.5\text{A}, V_{GS} = 0\text{V}$		-0.84	-1.2	V

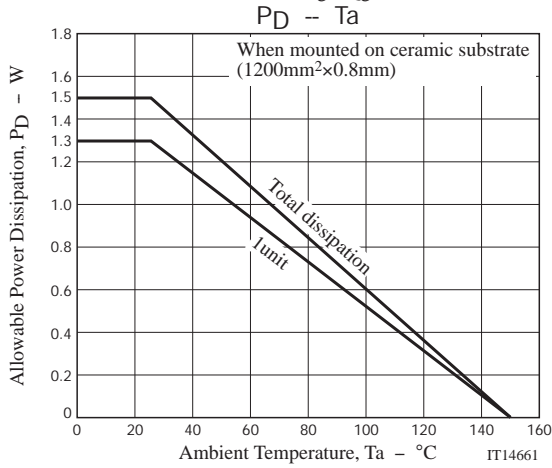
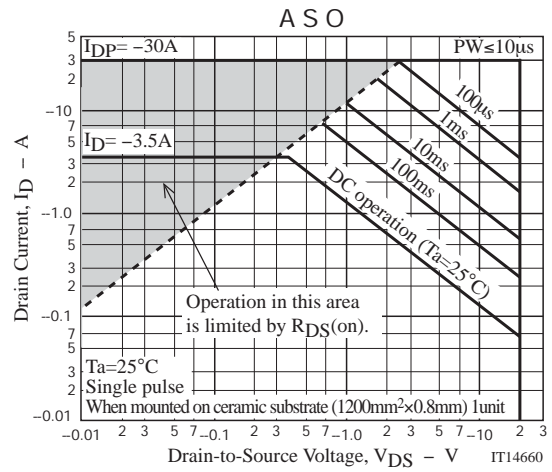
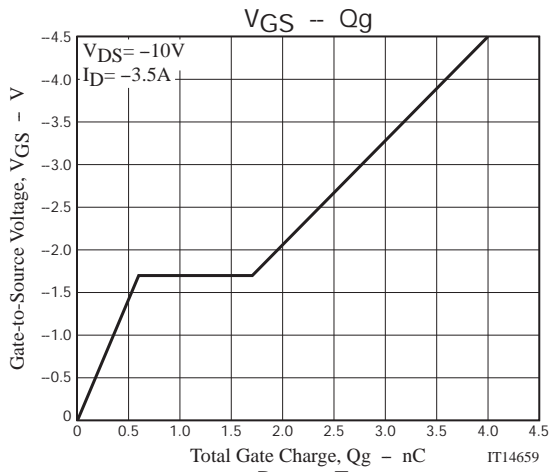
Switching Time Test Circuit



Ordering Information

Device	Package	Shipping	memo
ECH8672-TL-H	ECH8	3,000pcs./reel	Pb Free and Halogen Free





Embossed Taping Specification

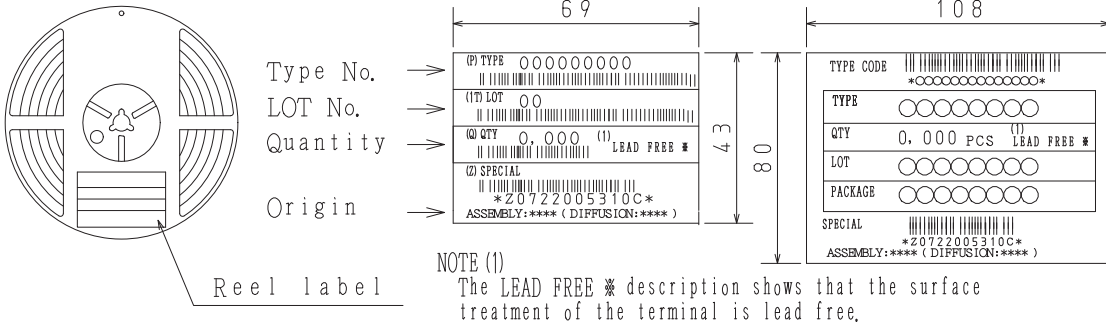
ECH8672-TL-H

1. Packing Format

Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
ECH8	CPH6	3,000	15,000	90,000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

Packing method

Reel label, Inner box label (unit:mm) Outer box label
 It is a label at the time of factory shipments.
 The form of a label may change in physical distribution process.

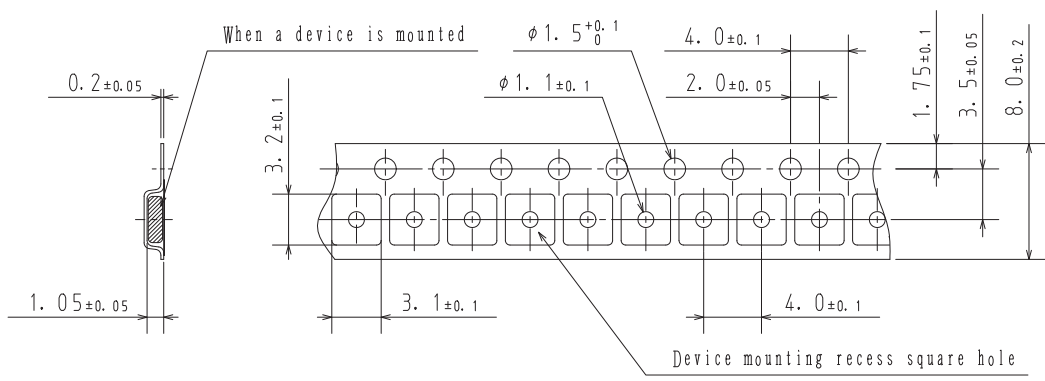


NOTE (1)
 The LEAD FREE * description shows that the surface treatment of the terminal is lead free.

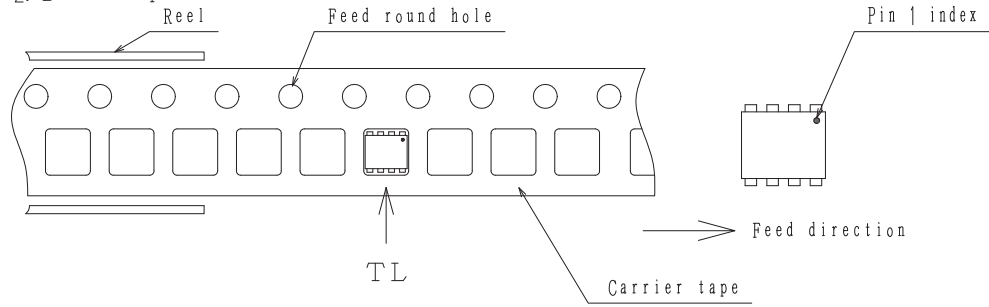
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping configuration

2-1. Carrier tape size (unit:mm)



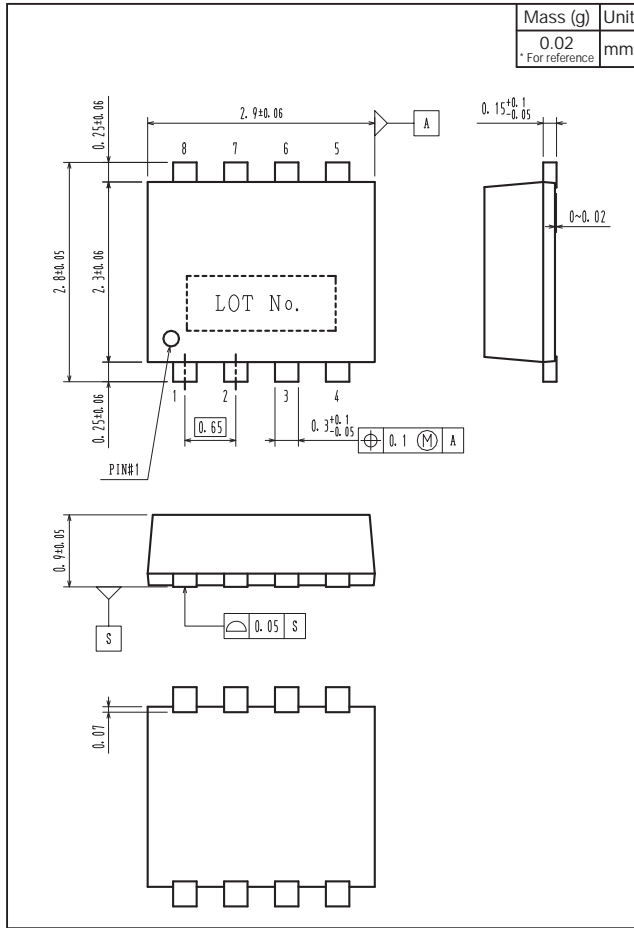
2-2. Device placement direction



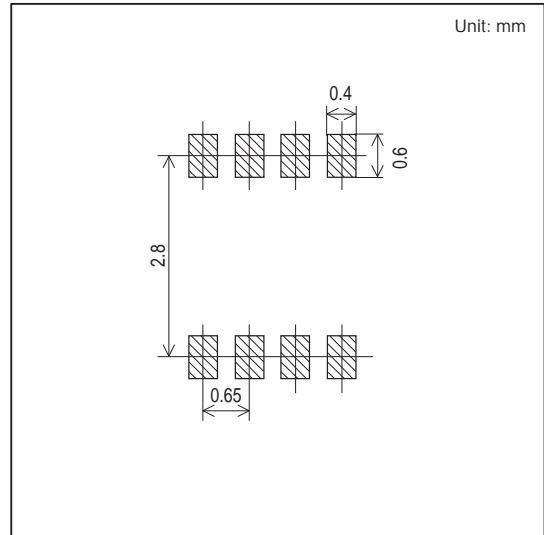
Those with pin 1 index on the feed hole side.....TL

Outline Drawing

ECH8672-TL-H



Land Pattern Example



Note on usage : Since the ECH8672 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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